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Exchange biased anisotropic magnetoresistance in Co/CoO bilayer<sup>1</sup> S. SAHOO, University of Nebraska-Lincoln, S. POLISETTY, YI WANG, T. MUKHERJEE, XI HE, CH. BINEK — We measured the anisotropic magnetoresistance of a Co(11nm)/CoO bilayer in exchange biased and unbiased states. The bilayer was fabricated on a-Al<sub>2</sub>O<sub>3</sub> substrate maintained at 300°C by molecular beam epitaxy at a base pressure of  $10^{-11}$ mbar.  $\theta$ -2 $\theta$  X-ray diffraction scans reveal hcp (001) texture of the Co film. No peak associated with the naturally formed CoO top layer was identified. Small angle X-ray reflectivity scans yield the Co and CoO thicknesses as 11 and 2.4nm, respectively. Exchange bias was obtained from field cooled magnetoresistance measurements at various temperatures carried out in a closed cycle cryostat. Exchange bias varies quasi linearly with temperature and vanishes at the blocking temperature,  $T_B$ =97K. The latter is less than 2/3 of the bulk Néel temperature allowing to estimate the T=0 antiferromagnetic correlation length of CoO to be 1.84 nm in accordance with the geometrical confinement.

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